Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-288-4166

view online at https://defobasegroup.com/non/coor of 200 4100	
Inclosure Material:	
Glass	
Overall Length:	
0.300 inches	
Terminal Length:	
1.500 inches	
Overall Diameter:	
0.130 inches	
Function For Which Designed:	
Voltage regulator	
Electrode Internally-electrically Connected To Case:	
Collector	
Mounting Method:	
Terminal	
Features Provided:	
Hermetically sealed case and quality assurance level tx	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
7.5 breakdown voltage, dc	
Voltage Tolerance In Percent:	
-5.0/+5.0	
Current Rating Per Characteristic:	
5.00 microamperes forward current, average peak	
Power Rating Per Characteristic:	
400.0 milliwatts small-signal input power, common-collector preset	
Maximum Operating Tempurature Per Measurement Point:	
175.0 degrees celsius ambient air	
Test Data Document:	
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type	data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type	data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).	
Terminal Type And Quantity:	
2 uninsulated wire lead	
Specification Data:	
81349-mil-s-19500/435 government specification	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	

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